Rec'c CT/PTO 08 NOV 2005 10/536696

Docket No.: 4590-410

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Inventor(s): Arnaud GRISARD et al.

Confirmation No. 2283

U.S. Patent Application No. 10/536,696

Filed: May 27, 2005

For: METHOD OF PRODUCING THICK NON-LINEAR OPTICAL GRATINGS

## **INFORMATION DISCLOSURE STATEMENT**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

Respectfully submitted,

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Date: November 8, 2005

## INFORMATION DISCLOSURE CITATION IN AN **APPLICATION**

ATTY. DOCKET NO. 4590-410

U.S. PATENT APPLICATION NO. 10/536,696

APPLICANT

Arnaud GRISARD et al.

FILING DATE

(PTO-1449)				FILING DATE May 27, 2005		GROUP	
		U.S. P	ATENT DOCUMENTS				
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE	
	5,349,466	09-20-1994	Delacourt, et al.				
		   FOREIG	N PATENT DOCUMENTS				
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.